Time-resolved photoemission study on strongly-correlated materials

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We developed two kinds of pump-proved photoemission systems. The pump-proved photoemission system using 6-eV probed light¹ is powerful for the precise measurement around Fermi level. The pump-proved photoemission system using 60-eV probed light² is powerful for the core level measurement. We would like to introduce the several time resolved photoemission results of strongly-correlated materials, such as VO₂, YbB₁₂, and YbAl₃, as well as TaS₂, Graphite, and topological insulators.

Figure 1 shows the time-resolved photoemission spectrum of valence-band of a VO₂ thin film.³ The transition was accompanied by a spectral-weight transfer on a 1-eV scale, which is characteristic of strong electron correlations. The photo-induced metallic state exhibited a unique spectrum that tails up to ~0.4 eV above E_F . This indicates that the emergent metallic state is different from the rutile state.

We will also introduce the hybridization gap formation in Kondo insulator YbB₁₂ using timeresolved photoemission spectroscopy.⁴

We would like to show the time-resolved photoemission of core level is also very powerful for several materials.

References



Fig.1 Photoinduced pase transition of VO₂.³

¹ Ishida, et.al., Scientific Reports **1**, 64 (2011).

² Ishizaka, et. al., Phys Rev. B 83, (2011) 081104

³ Yoshida, et. al., Phys Rev. B **89**, 205114 (2014).

⁴ Okawa, et al., arXiv:1407.0578